

### FEATURES

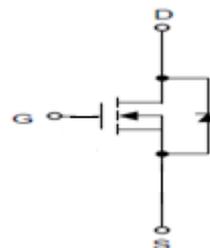
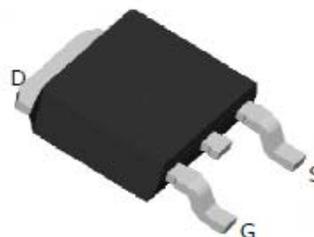
- 30V/60A  
 $R_{DS(ON)} = 9\text{m}\Omega \text{ typ@ } V_{GS}=10\text{V}$   
 $R_{DS(ON)} = 11.5\text{m}\Omega \text{ typ@ } V_{GS}=4.5\text{V}$

- Lead free and Green Device Available

### Application

- Load Switch

### PIN DESCRIPTION



### Absolute Maximum Ratings ( $T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Maximum	Unit	
$V_{DSS}$	Drain-to-Source Voltage	30	V	
$V_{GSS}$	Gate-to-Source Voltage	$\pm 20$	V	
$I_D$	Continuous Drain Current	$T_C=25^\circ\text{C}$	60	A
		$T_C=100^\circ\text{C}$	37	A
$I_{DP}$	Pulsed Drain Current	$T_C=25^\circ\text{C}$	35	A
PD	Maximum Power Dissipation	$T_C=25^\circ\text{C}$	54	W
		$T_C=100^\circ\text{C}$	21	
$T_J, T_{STG}$	Junction & Storage Temperature Range	-55~150	$^\circ\text{C}$	

### Thermal Characteristics

Symbol	Parameter	Typical	Unit
$R_{\theta jc}$	Thermal Resistance-Junction to Case	2.3	$^\circ\text{C}/\text{W}$
$R_{\theta ja}$	Thermal Resistance-Junction to Ambient	62.5	

### Electrical Characteristics (TA=25°C unless otherwise noted)

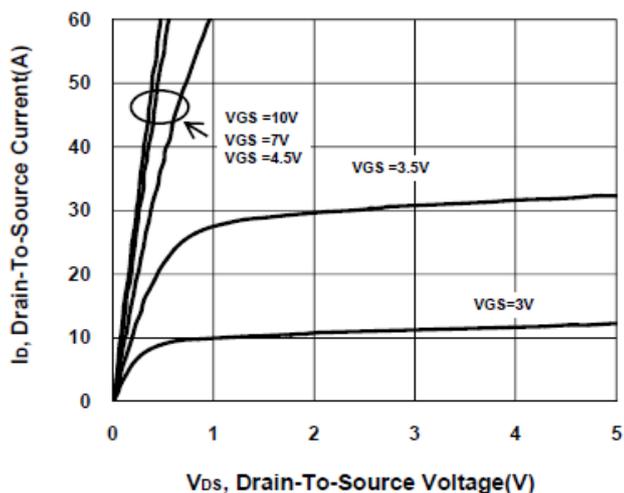
Symbol	Parameter	Test Conditions	Min.	Typ	Max.	Unit
<b>Static Characteristics</b>						
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	30	—	—	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V	—	—	1	uA
		T <sub>J</sub> =85°C	—	—	10	
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	1	1.7	3	V
I <sub>GSS</sub>	Gate Leakage Current	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	—	—	±100	nA
R <sub>DS(on)</sub> <sup>1</sup>	Drain-Source On-Resistance	V <sub>GS</sub> =10V, I <sub>D</sub> =15A	—	8.5	10	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =15A	—	12	15	
<b>Diode Characteristics</b>						
V <sub>SD</sub> <sup>1</sup>	Diode Forward Voltage	I <sub>SD</sub> =15A, V <sub>GS</sub> =0V	—	0.88	1.3	V
I <sub>S</sub>	Diode Continuous Forward Current				60	A
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> =15A,	—	23		ns
Q <sub>rr</sub>	Reverse Recovery Charge	dI/dt=100A/us	—	15		nC
<b>Dynamic Characteristics<sup>2</sup></b>						
R <sub>G</sub>	Gate Resistance	V <sub>GS</sub> =0V, V <sub>DS</sub> =0V, Frequency=1MHz	—	1.5	—	Ω
C <sub>iss</sub>	Input Capacitance	V <sub>GS</sub> =0V, V <sub>DS</sub> =30V Frequency=1MHz	—	920		pF
C <sub>oss</sub>	Output Capacitance		—	187		
C <sub>rss</sub>	Reverse Transfer Capacitance		—	130		
t <sub>d(on)</sub>	Turn-On Delay Time	V <sub>DD</sub> =15V, R <sub>L</sub> =30Ω I <sub>D</sub> =15A, V <sub>GS</sub> =10V R <sub>G</sub> =6Ω	—	15		ns
t <sub>r</sub>	Turn-On Rise Time		—	25		
t <sub>d(off)</sub>	Turn-Off Delay Time		—	60		
t <sub>f</sub>	Turn-Off Fall Time		—	17		
<b>Gate Charge Characteristics<sup>2</sup></b>						
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> =15V, V <sub>GS</sub> =10V I <sub>D</sub> =15A	—	22		nC
Q <sub>gs</sub>	Gate-to-Source Charge		—	5		
Q <sub>gd</sub>	Gate-to-Drain Charge		—	6.5		

Note: 1: Pulse test; pulse width ≤ 300ns, duty cycle ≤ 2%.

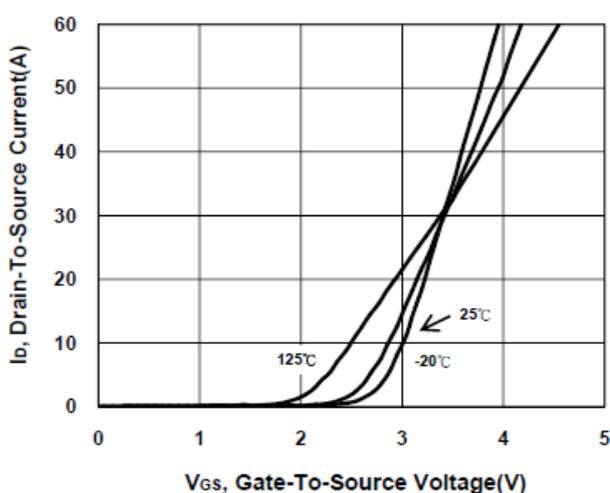
2: Guaranteed by design, not subject to production testing.

## Typical Operating Characteristics

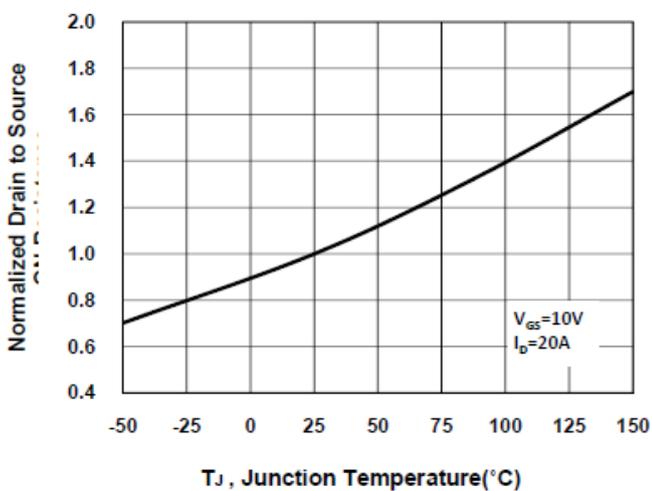
### Output Characteristics



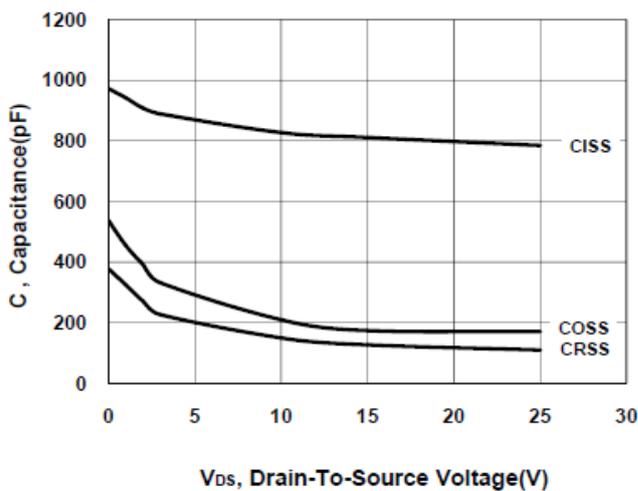
### Transfer Characteristics



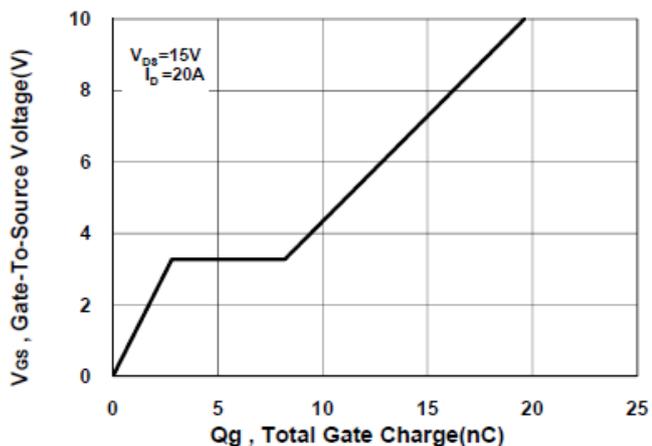
### On-Resistance VS Temperature



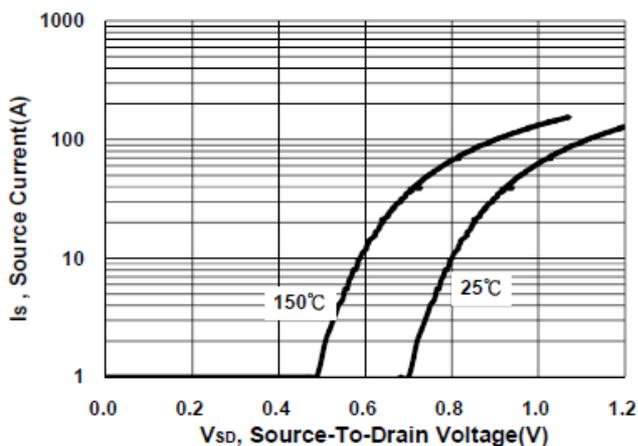
### Capacitance Characteristic



### Gate charge Characteristics

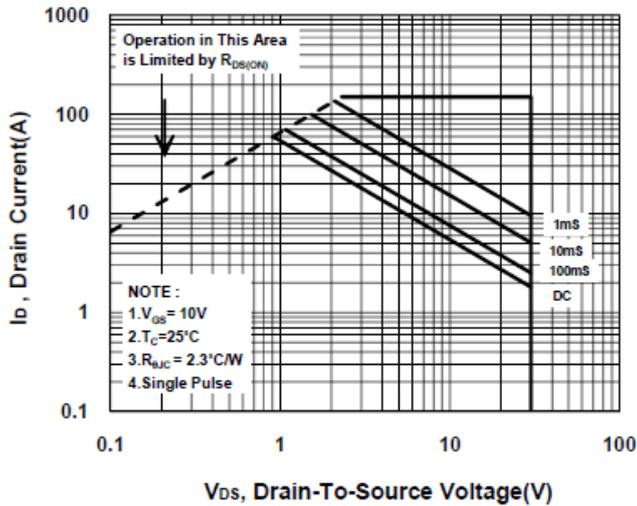


### Source-Drain Diode Forward Voltage

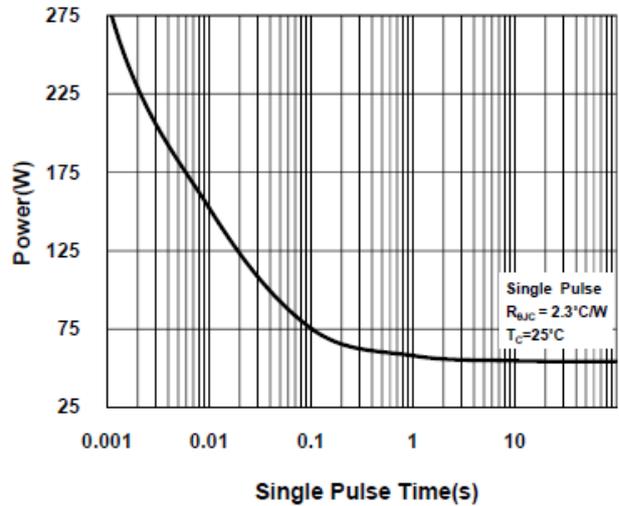


## Typical Operating Characteristics

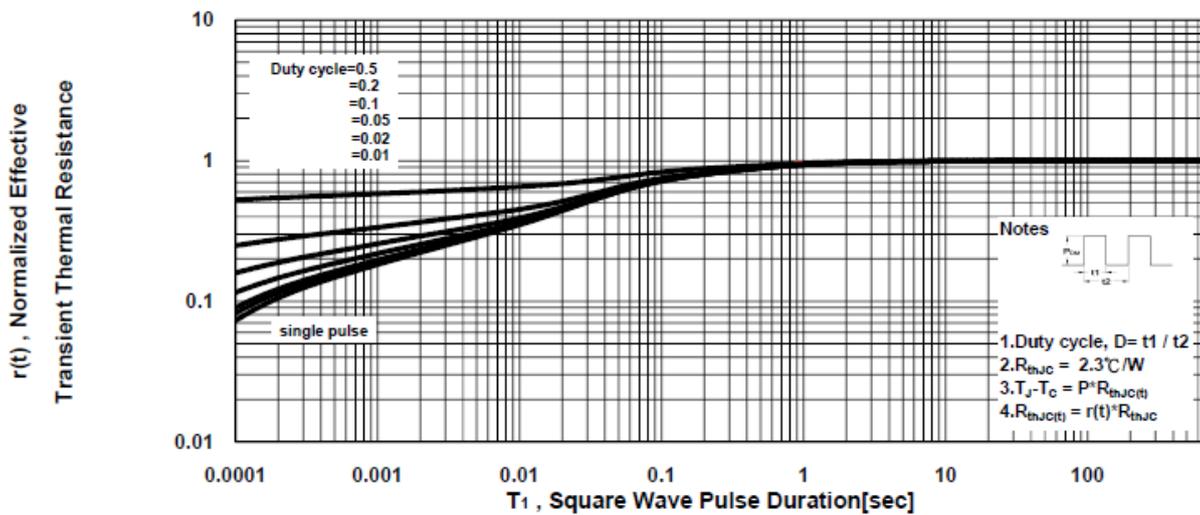
### Safe Operating Area



### Single Pulse Maximum Power Dissipation

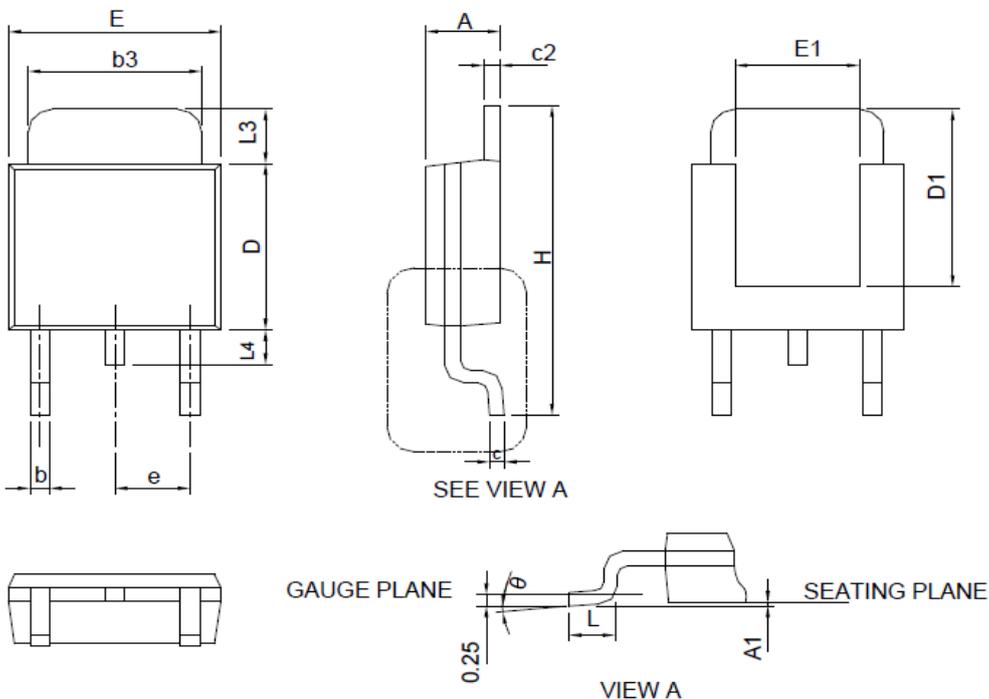


### Transient Thermal Response Curve



### Package Information

TO-252-3



SYMBOL	TO-252-3			
	MILLIMETERS		INCHES	
	MIN.	MAX.	MIN.	MAX.
A	2.18	2.39	0.086	0.094
A1		0.13		0.005
b	0.50	0.89	0.020	0.035
b3	4.95	5.46	0.195	0.215
c	0.46	0.61	0.018	0.024
c2	0.46	0.89	0.018	0.035
D	5.33	6.22	0.210	0.245
D1	4.57	6.00	0.180	0.236
E	6.35	6.73	0.250	0.265
E1	3.81	6.00	0.150	0.236
e	2.29 BSC		0.090 BSC	
H	9.40	10.41	0.370	0.410
L	0.90	1.78	0.035	0.070
L3	0.89	2.03	0.035	0.080
L4		1.02		0.040
θ	0°	8°	0°	8°

Note : Follow JEDEC TO-252 .